## ANL: Photocathodes for ultrahigh brightness sources

- Surface lab UV ARPES, XPS UHV chambers to be used to characterize photocathode emittance. K. Harkay, R. Rosenberg, M. White (ANL); L. Spentzouris, J. Terry (IIT)
- Explore novel cathode designs theoretically to optimize/minimize emittance. K. Nemeth
- Modify existing cathode properties (e.g. lower work function of Cs<sub>2</sub>Te). K. Nemeth (ANL),
   J. Terdik (U of C)



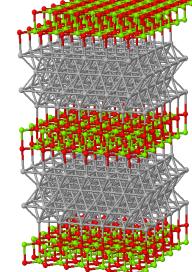
UV ARPES chamber under commissioning (designed by R. Rosenberg)

Proc. 2009 PAC (MO6RFP045)

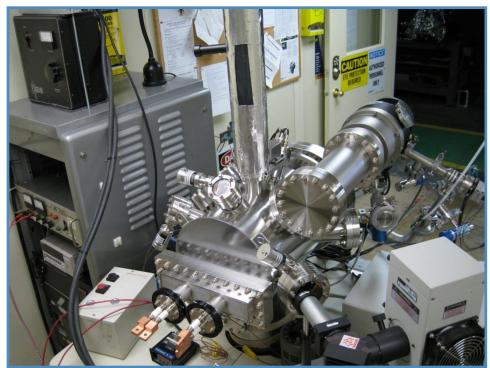
Potential low-transverse-emittance layered structure: K. Nemeth et al., PRL 104, 046801 (2010).

MgO(100)2L-Ag(100)4L-MgO(100)2L; DFT(PW91)
Work function reduced by ~1 eV relative to Ag(001)
Normalized emittance
0.05 mm-mr/mm

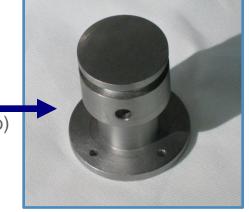
Preliminary idea from surface catalysis systems [L. Giordano et al., J. Chem. Phys. 127, 144713 (2007)].



## ANL: High QE Photocathode - Fabrication and Vacuum Transfer



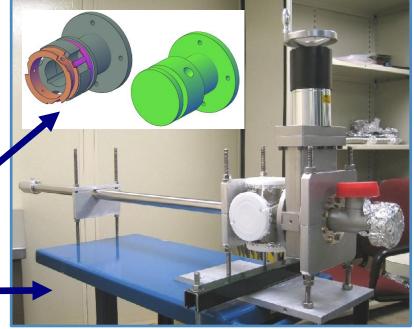
Photocathode plug/substrate (Mo)





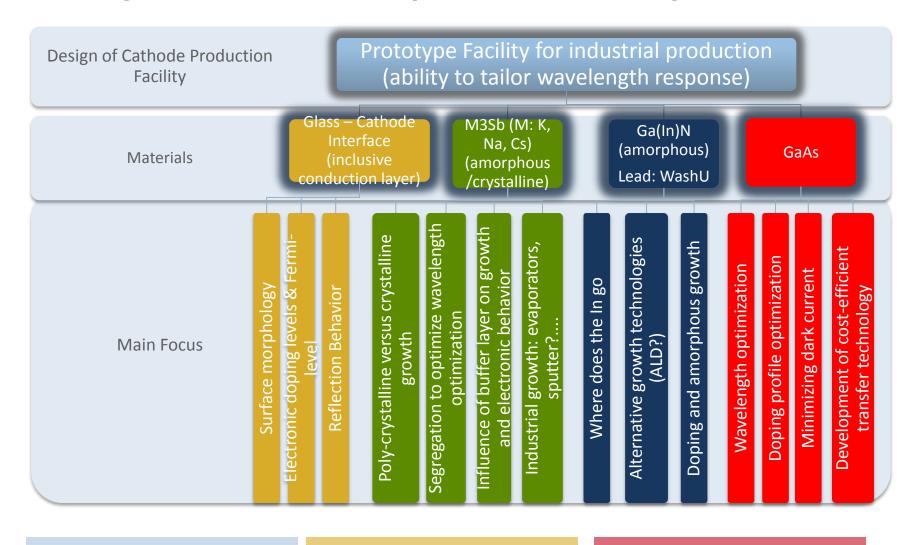
Universal design for HEP-MSD-APS transfer

Cs<sub>2</sub>Te UHV vacuum transfer system to rf gun



Z. Yusof, http://www.hep.anl.gov/eyurtsev/psec; I. Veryovkin

## ANL: Large-scale cathodes optimized for fast photodetectors



**SSL**Basic Design

ANL/WashU/UIUC
Theory Inspired Design

**ANL**Industrial Production